AC6329B Datasheet

Zhuhai Jieli Technology Co.,LTD

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AC6329B Features

High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

Flexible I/O

- 9 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

Peripheral Feature

- One Full Speed USB OTG controller
- Four Multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex advanced UART(DMA)
- One IIC interface supports host and device mode
- RTC, with alarm clock and time base to wake up the chip
- 16-bit PWM generator for motor driving
- Three IQ Encoder
- 7 channels 10-bit ADC
- 1 channel 8 levels Low Power Detector

- Embedded PMU support low power mode
- 1 Crystal Oscillator
- Watchdog
- Power-on reset

Bluetooth Feature

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth
- **▼** V5.0+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides +8dbm transmitting power
- Receiver with -92dBm sensitivity
- Support a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\ gatt\rfcomm\sdp\l2cap profile

Power Supply

VDDIO is 1.8V to 3.4V

Packages

SOP16

Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

1. Block Diagram

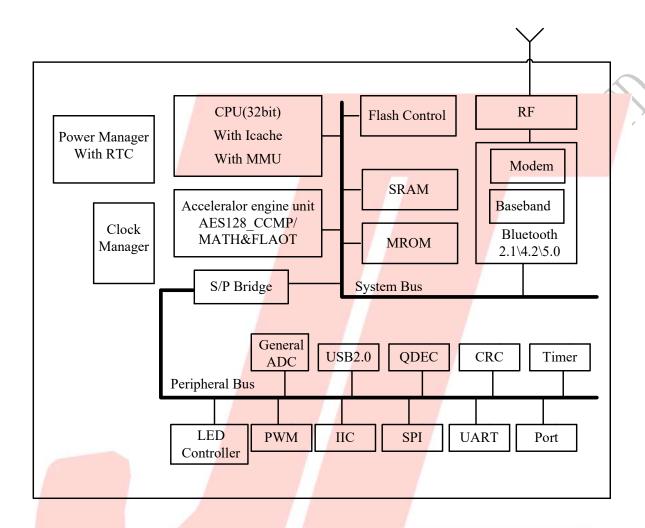


Figure 1-1 AC6329B_SOP16 Block Diagram

2. Pin Definition

2.1 Pin Assignment

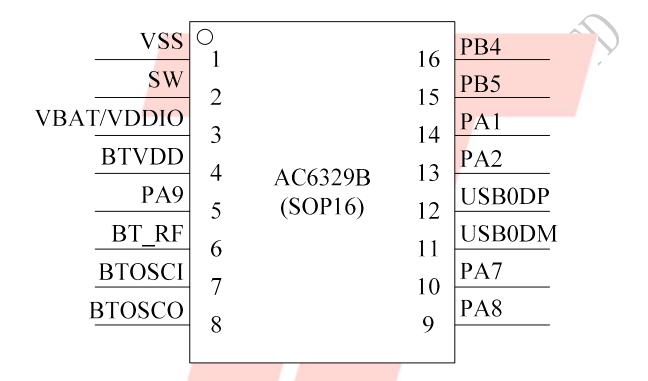


Figure 2-1 AC6329B_SOP16 Package Diagram

2.2 Pin Description

Table 2-1 AC6329B_SOP16 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	VSS	P	GND	
2	SW	P	DC-DC Switch Pin	-
	VBAT	P	LDO Power	-
3	VDDIO	P	IO Power 3.3V	-
4	BTAVDD	P	Core Power 1.3V	-
5	PA9	I/O	GPIO (pull up)	Long Press Reset; ADC8: ADC Channel 8;
6	BT_RF	-	RF Antenna	-
7	BTOSCI	I	BTOSCI	- /
8	BTOSCO	О	BTOSCO	-
9	PA8	I/O	GPIO	TMR3: Timer3 Clock In; IIC_SDA_C: IIC SDA(C); ADC4: ADC Channel 4; UART1_RXC: Uart1 Data In(C); PWMCH1L;
10	PA7	I/O	GPIO	TMR1: Timer1 Clock In; IIC_SCL_C: IIC SCL(C); ADC3: ADC Channel 3; UART1_TXC: Uart1 Data Out(C); PWMCH1H;
11	USB0DM	I/O	GPIO (pull down)	IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);
12	USB0DP	I/O	GPIO (pull down)	IIC_SCL_A: IIC SCL(A); ADC10: ADC Channel 10; UART1_TXD: Uart1 Data Out(D);
13	PA2	I/O	GPIO	CAP3: Timer3 Capture; Q-decoder0_1; UART0_RXC: Uart0 Data In(C); UART1_RTS;

				PWM0: Timer0 PWM Output;
				Q-decoder0_0;
14	PA1	I/O	GPIO	ADC0: ADC Channel 0;
				UART0_TXC: Uart0 Data Out(C);
				UART1_CTS;
			CDIO	UART1_RXA: Uart1 Data In(A);
15	PB5	I/O	GPIO	Q-decoder2_1;
			(High Voltage)	PWMCH3L;
		/		TMR2: Timer2 Clock In;
				Q-decoder2_0;
16	PB4	I/O	GPIO	ADC9: ADC Channel 9;
				UAR1_TXA: Uart1 Data Out(A);
				PWMCH3H;

3. Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VDDIO	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 Recommended Operating Conditions

Table 3-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VDDIO	Voltage input	1.8	3.0	3.4	V	
BTAVDD	Voltage output	1	1.3	1.4	V	DC-DC mode: 40mA loading

3.3 IO Input/Output Electrical Logical Characteristics

Table 3-3

IO input characteristics									
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions			
V _{IL}	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V			
$ m V_{IH}$	High-Leve <mark>l Input</mark> Volta <mark>ge</mark>	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V			
IO output	characterist <mark>ics</mark>								
$ m V_{OL}$	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V			
Voh	High-Level Output Voltage	2.7	_	7-/	V	VDDIO = 3.3V			

3.4 Internal Resistor Characteristics

Table 3-4

Po	ort	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
	-PA9, B4	drive_select[11] 24mA drive_select[10] 24mA (with 120ohm res) drive_select[01] 8mA drive_select[00] 8mA (with 120ohm res)	10K	10K	1. PA9 default pull up 2. USB0DM&USB0DP default pull down 3. Internal pull-up/pull-down resistance accuracy ±20%
PI	B5	8mA	10K	10K	5.PB5 can pull-up resistance
USB	BODP	4mA	1.5K	15K	to 5V
USB	0DM	4mA	180K	15K	

3.5 BT Characteristics

3.5.1 Transmitter

Basic Data Rate

Table 3-5

Parameter		Min	Тур	Max	Unit	Test Conditions
RF Transmit Power			4	6	dBm	25°C,
RF Power Contro	l Range		20		dB	Power Supply
20dB Bandw	idth		950		KHz	
Adjacent Channel	+2MHz		-40		dBm	VDDIO=3.3V
Transmit Power	-2MHz		-38		dBm	2441MHz

+3MHz	-44	dBm
-3MHz	-35	dBm

Enhanced Data Rate

Table 3-6

Ennuncea Bata Rate				0100			
Parameter			in	Тур	Max	Unit	Test Conditions
Relative Power				-1		dB	
π/4 DQPSK	DEVM RMS			7		%	
	DEVM 99%			12		%	25°C,
Modulation Accuracy	DEVM Peak			17		%	Power Supply
	+2MHz			-40		dBm	VDDIO=3.3V
Adjacent Channel	-2MHz		1	-38		dBm	2441MHz
Transmit Power	+3MHz			-44		dBm	
	-3MHz			-35		dBm	

3.6.2 Receiver

Basic Data Rate

Table 3-8

Busic Butu Itute			DIC C O			
Paramete	Min	Тур	Max	Unit	Test Conditions	
Sensitivit		-92		dBm		
Co-channel Interferen		-9		dB		
	+1MHz		+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37	7	dB	VDDIO=3.3V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz	7/	+40	N/	dB	
	-3MHz	7/	+35		dB	

Enhanced Data Rate

Table 3-9

Paramete	Min	Тур	Max	Unit	Test Conditions	
Sensitivit		-92		dBm		
Co-channel Interferen		-9		dB		
	+1MHz		+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VDDIO=3.3V
Interference Rejection	Interference Rejection -2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

4. Package Information

4.1 SOP16(4mm*4mm)

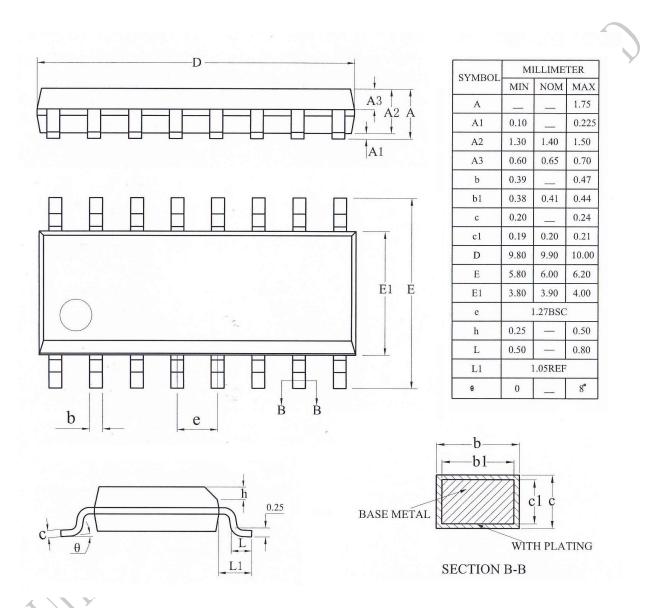


Figure 4-1 AC6329B_SOP16 Package

5. Package Type Specification



- ①Represents different packages
- ②Represents different memory sizes

2: 2Mbit Flash

6. Revision History

Date	Revision	Description
2021.03.12	V1.0	Initial Release